Digital Transistors (BRT) R1 = 100 k Ω , R2 = ∞ k Ω

NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a baseemitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

| Rating | Symbol | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage | V_{CBO} | 50 | Vdc |
| Collector–Emitter Voltage | V_{CEO} | 50 | Vdc |
| Collector Current – Continuous | IC | 100 | mAdc |
| Input Forward Voltage | V _{IN(fwd)} | 40 | Vdc |
| Input Reverse Voltage | V _{IN(rev)} | 6 | Vdc |

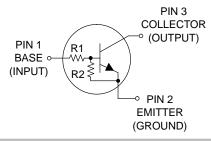
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

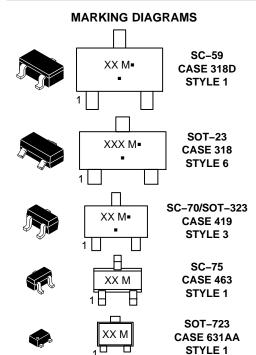


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PIN CONNECTIONS





= Specific Device Code XXX

CASE 524AA STYLE 1

SOT-1123

(Note: Microdot may be in either location)

= Date Code*

= Pb-Free Package

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

Μ

Table 1. ORDERING INFORMATION

| Device | Part Marking | Package | Shipping [†] |
|---------------|--------------|----------------------------|-----------------------|
| MUN2241T1G | 8U | SC-59 (Pb-Free) | 3000 / Tape & Reel |
| MMUN2241LT1G | A8U | SOT-23 (Pb-Free) | 3000 / Tape & Reel |
| MUN5241T1G | AW | SC-70/SOT-323 (Pb-Free) | 3000 / Tape & Reel |
| DTC115TET1G | 7V | SC-75 (Pb-Free) | 3000 / Tape & Reel |
| DTC115TM3T5G | 7D | SOT-723 (Pb-Free) | 8000 / Tape & Reel |
| NSBC115TF3T5G | P (90°)* | SOT-1123 (Pb-Free) | 8000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*} (xx°) = Degree rotation in the clockwise direction.

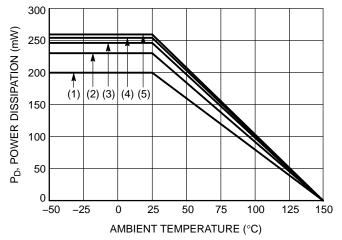


Figure 1. Derating Curve

- (1) SC-75 and SC-70/SOT323; Minimum Pad
- (2) SC-59; Minimum Pad
- (3) SOT-23; Minimum Pad
- (4) SOT-1123; 100 mm², 1 oz. copper trace
- (5) SOT-723; Minimum Pad

Table 2. THERMAL CHARACTERISTICS

| Characteristic | | Symbol | Max | Unit |
|--|--|-----------------------------------|--------------------------|-------------|
| THERMAL CHARACTERISTICS (SC-59) (MUN2241) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C | (Note 1) (Note 2) (Note 1) (Note 2) | P _D | 230 338 1.8 2.7 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{	heta JA}$ | 540 370 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 1) (Note 2) | $R_{	hetaJL}$ | 264 287 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SOT-23) (MMUN2241L) | | | | |
| Total Device Dissipation T _A = 25°C Derate above 25°C | (Note 1) (Note 2) (Note 1) (Note 2) | P _D | 246 400 2.0 3.2 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{	hetaJA}$ | 508 311 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 1) (Note 2) | $R_{	hetaJL}$ | 174 208 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5241) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C | (Note 1) (Note 2) (Note 1) (Note 2) | P _D | 202 310 1.6 2.5 | mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{	heta JA}$ | 618 403 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 1) (Note 2) | $R_{	heta JL}$ | 280 332 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SC-75) (DTC115TE) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C | (Note 1) (Note 2) (Note 1) (Note 2) | P _D | 200 300 1.6 2.4 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{	heta JA}$ | 600 400 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |
| THERMAL CHARACTERISTICS (SOT-723) (DTC115TM3) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C | (Note 1) (Note 2) (Note 1) (Note 2) | P _D | 260 600 2.0 4.8 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 1) (Note 2) | $R_{	hetaJA}$ | 480 205 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |

- 1. FR-4 @ Minimum Pad.
- FR-4 @ 1.0 x 1.0 Inch Pad.
 FR-4 @ 100 mm², 1 oz. copper traces, still air.
 FR-4 @ 500 mm², 1 oz. copper traces, still air.

Table 2. THERMAL CHARACTERISTICS

| Characteristic | | Symbol | Max | Unit |
|--|--|-----------------------------------|--------------------------|-------------|
| THERMAL CHARACTERISTICS (SOT-1123) (NSBC115TF3) | | | | |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C | (Note 3) (Note 4) (Note 3) (Note 4) | P _D | 254 297 2.0 2.4 | mW mW/°C |
| Thermal Resistance, Junction to Ambient | (Note 3) (Note 4) | $R_{	heta JA}$ | 493 421 | °C/W |
| Thermal Resistance, Junction to Lead | (Note 3) | $R_{	heta JL}$ | 193 | °C/W |
| Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to +150 | °C |

- 1. FR-4 @ Minimum Pad.
- 2. FR-4 @ 1.0 x 1.0 Inch Pad.
- FR-4 @ 100 mm², 1 oz. copper traces, still air.
 FR-4 @ 500 mm², 1 oz. copper traces, still air.

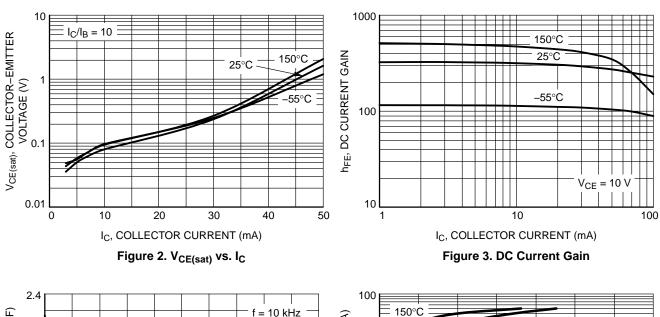
Table 3. ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|---|--------------------------------|-----|-----|------|------|
| OFF CHARACTERISTICS | <u>.</u> | | | | |
| Collector–Base Cutoff Current (V _{CB} = 50 V, I _E = 0) | I _{CBO} | _ | _ | 100 | nAdc |
| Collector–Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$ | I _{CEO} | _ | _ | 500 | nAdc |
| Emitter-Base Cutoff Current (V _{EB} = 6.0 V, I _C = 0) | I _{EBO} | _ | _ | 0.1 | mAdc |
| Collector–Base Breakdown Voltage ($I_C = 10 \mu A, I_E = 0$) | V _(BR) CBO | 50 | _ | _ | Vdc |
| Collector–Emitter Breakdown Voltage (Note 5) (I _C = 2.0 mA, I _B = 0) | V _(BR) CEO | 50 | _ | - | Vdc |
| ON CHARACTERISTICS | <u>.</u> | | | | |
| DC Current Gain (Note 5) (I _C = 5.0 mA, V _{CE} = 10 V) | h _{FE} | 160 | 350 | - | |
| Collector–Emitter Saturation Voltage (Note 5) (I _C = 10 mA, I _B = 5.0 mA) | V _{CE(sat)} | _ | _ | 0.25 | Vdc |
| Input Voltage (off) ($V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}$) | V _{i(off)} | _ | 0.6 | 0.5 | Vdc |
| Input Voltage (on) (V _{CE} = 0.3 V, I _C = 1.0 mA) | V _{i(on)} | 1.5 | 1.0 | - | Vdc |
| Output Voltage (on) (V _{CC} = 5.0 V, V _B = 5.0 V, R _L = 1.0 k Ω) | V _{OL} | _ | _ | 0.2 | Vdc |
| Output Voltage (off) ($V_{CC} = 5.0 \text{ V}, V_B = 0.25 \text{ V}, R_L = 1.0 \text{ k}\Omega$) | V _{OH} | 4.9 | _ | - | Vdc |
| Input Resistor | R1 | 70 | 100 | 130 | kΩ |
| Resistor Ratio | R ₁ /R ₂ | _ | - | - | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle ≤ 2%.

TYPICAL CHARACTERISTICS - NSBC115TF3



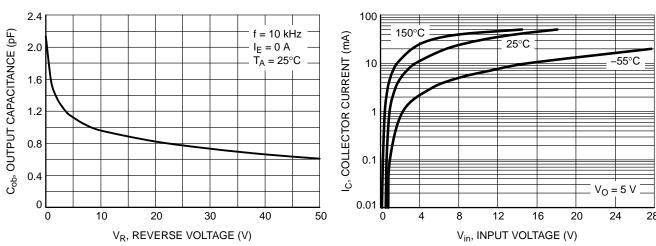


Figure 4. Output Capacitance

Figure 5. Output Current vs. Input Voltage

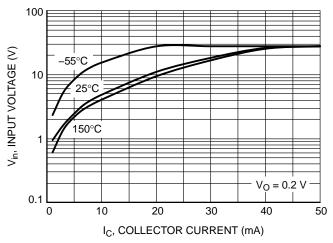


Figure 6. Input Voltage vs. Output Current

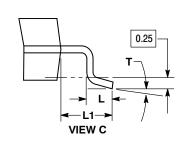


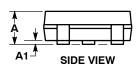
SOT-23 (TO-236) CASE 318-08 **ISSUE AS**

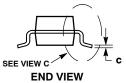
DATE 30 JAN 2018

SCALE 4:1 D - 3X b

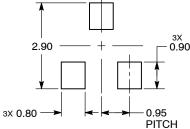
TOP VIEW







RECOMMENDED SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

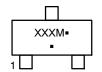
3. ANODE

NOTES:

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | | | INCHES | |
|-----|-------------|------|------|-------|--------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| С | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| е | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| Т | O٥ | | 100 | O٥ | | 10° |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE | ı | |
|---|---|---|---|------------------|------------------|
| STYLE 9: | STYLE 10: | STYLE 11: | STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE | STYLE 13: | STYLE 14: |
| PIN 1. ANODE | PIN 1. DRAIN | PIN 1. ANODE | | PIN 1. SOURCE | PIN 1. CATHODE |
| 2. ANODE | 2. SOURCE | 2. CATHODE | | 2. DRAIN | 2. GATE |
| 3. CATHODE | 3. GATE | 3. CATHODE-ANODE | | 3. GATE | 3. ANODE |
| STYLE 15: | STYLE 16: | STYLE 17: | STYLE 18: | STYLE 19: | STYLE 20: |
| PIN 1. GATE | PIN 1. ANODE | PIN 1. NO CONNECTION | PIN 1. NO CONNECTION | I PIN 1. CATHODE | PIN 1. CATHODE |
| 2. CATHODE | 2. CATHODE | 2. ANODE | 2. CATHODE | 2. ANODE | 2. ANODE |
| 3. ANODE | 3. CATHODE | 3. CATHODE | 3. ANODE | 3. CATHODE-ANODE | 3. GATE |
| STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: | STYLE 25: | STYLE 26: |
| PIN 1. GATE | PIN 1. RETURN | PIN 1. ANODE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE |
| 2. SOURCE | 2. OUTPUT | 2. ANODE | 2. DRAIN | 2. CATHODE | 2. ANODE |
| 3. DRAIN | 3. INPUT | 3. CATHODE | 3. SOURCE | 3. GATE | 3. NO CONNECTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE | | | | |

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|------------------|-----------------|--|-------------|--|
| DESCRIPTION: | SOT-23 (TO-236) | | PAGE 1 OF 1 | |

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3. CATHODE



SCALE 2:1

SC-59 CASE 318D-04 ISSUE H

DATE 28 JUN 2012

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

| | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|--------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | MOM | MAX |
| Α | 1.00 | 1.15 | 1.30 | 0.039 | 0.045 | 0.051 |
| A1 | 0.01 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.35 | 0.43 | 0.50 | 0.014 | 0.017 | 0.020 |
| С | 0.09 | 0.14 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.70 | 2.90 | 3.10 | 0.106 | 0.114 | 0.122 |
| E | 1.30 | 1.50 | 1.70 | 0.051 | 0.059 | 0.067 |
| е | 1.70 | 1.90 | 2.10 | 0.067 | 0.075 | 0.083 |
| L | 0.20 | 0.40 | 0.60 | 0.008 | 0.016 | 0.024 |
| HE | 2.50 | 2.80 | 3.00 | 0.099 | 0.110 | 0.118 |

GENERIC MARKING DIAGRAM

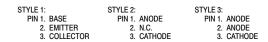


XXX = Specific Device Code

Μ = Date Code = Pb-Free Package*

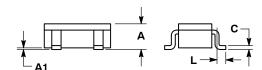
(*Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

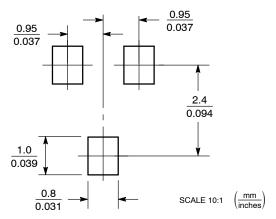


| STYLE 4: | STYLE 5: | STYLE 6: |
|-------------------------|----------------|---------------------------------|
| PIN 1. CATHODE | PIN 1. CATHODE | PIN 1. ANODE |
| 2. N.C. | 2. CATHODE | 2. CATHODE |
| ANODE | 3. ANODE | ANODE/CATHODE |

Ε ΗE



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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|------------------|-------------|--|-------------|--|
| DESCRIPTION: | SC-59 | • | PAGE 1 OF 1 | |

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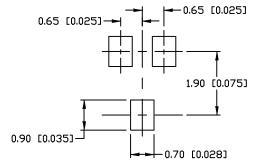
SC-70 (SOT-323) **CASE 419 ISSUE P**

DATE 07 OCT 2021

NOTES:

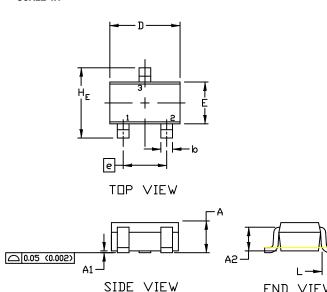
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

| | MILLIMETERS | | | | INCHES | |
|--------------|-------------|--------------------------|------|-------|----------------------------|-------------------|
| DIM | MIN. | N□M. | MAX. | MIN. | N□M. | MAX. |
| Α | 0.80 | 0.90 | 1.00 | 0.032 | 0.035 | 0.040 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| A2 | | 0.70 REF | | | 0.028 BS | С |
| b | 0.30 | 0.35 | 0.40 | 0.012 | 0.014 | 0.016 |
| С | 0.10 | 0.18 | 0.25 | 0.004 | 0.007 | 0.010 |
| D | 1.80 | 2.10 | 2.20 | 0.071 | 0.083 | 0.087 |
| E | 1.15 | 1.24 | 1.35 | 0.045 | 0.049 | 0.053 |
| e | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e1 | 0.65 BSC | | | | 0.026 BS | C |
| L | 0.20 | 0.38 | 0.56 | 0.008 | 0.015 | 0.022 |
| HE | 2.00 | 2.10 | 2.40 | 0.079 | 0.083 | 0.095 |
| e e1 L | 1.20 | 1.30 0.65 BSC 0.38 | 1.40 | 0.047 | 0.051 0.026 BS 0.015 | 0.05 C 0.02 |



For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM



XX = Specific Device Code

= Date Code М

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

| STYLE 1: CANCELLED | STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE | STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE | STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE | |
|-----------------------|---|---|--|--|----------------|
| STYLE 6: | STYLE 7: | STYLE 8: | STYLE 9: | STYLE 10: | STYLE 11: |
| PIN 1. EMITTER | PIN 1. BASE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. CATHODE |
| 2. BASE | 2. EMITTER | 2. SOURCE | 2. CATHODE | 2. ANODE | 2. CATHODE |
| 3. COLLECTOR | 3. COLLECTOR | 3. DRAIN | 3. CATHODE-ANODE | 3. ANODE-CATHODE | 3. CATHODE |

END VIEW

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|------------------|-----------------|--|-------------|
| DESCRIPTION: | SC-70 (SOT-323) | | PAGE 1 OF 1 |

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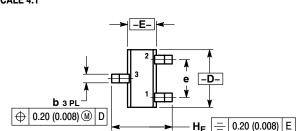
MECHANICAL CASE OUTLINE

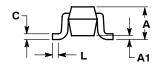




SC-75/SOT-416 CASE 463-01 **ISSUE G**

DATE 07 AUG 2015





STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

PIN 1. CATHODE 2. CATHODE 3. ANODE

STYLE 4:

STYLE 5:

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE

PIN 1. GATE 2. SOURCE 3. DRAIN

STYLE 3: PIN 1. ANODE 2. ANODE

3. CATHODE

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

| | MILLIMETERS | | INCHES | | ; | |
|-----|-------------|------|--------|---------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.70 | 0.80 | 0.90 | 0.027 | 0.031 | 0.035 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.15 | 0.20 | 0.30 | 0.006 | 0.008 | 0.012 |
| С | 0.10 | 0.15 | 0.25 | 0.004 | 0.006 | 0.010 |
| D | 1.55 | 1.60 | 1.65 | 0.061 | 0.063 | 0.065 |
| E | 0.70 | 0.80 | 0.90 | 0.027 | 0.031 | 0.035 |
| е | 1.00 BSC | | | .04 BS0 | | |
| Ĺ | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| HE | 1.50 | 1.60 | 1.70 | 0.060 | 0.063 | 0.067 |

GENERIC MARKING DIAGRAM*



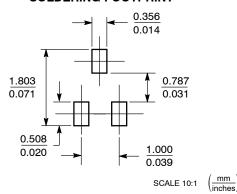
XX= Specific Device Code

Μ = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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| DESCRIPTION: | SC-75/SOT-416 | | PAGE 1 OF 1 | |

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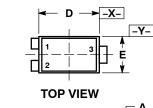


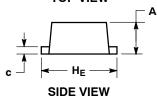


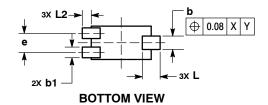
SOT-1123 CASE 524AA ISSUE C

DATE 29 NOV 2011

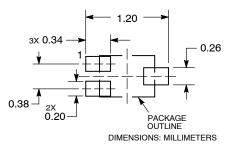
SCALE 8:1







SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE
- MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
 FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | |
|-----|-------------|------|--|
| DIM | MIN | MAX | |
| Α | 0.34 | 0.40 | |
| b | 0.15 | 0.28 | |
| b1 | 0.10 | 0.20 | |
| С | 0.07 | 0.17 | |
| D | 0.75 | 0.85 | |
| E | 0.55 | 0.65 | |
| е | 0.35 | 0.40 | |
| HE | 0.95 | 1.05 | |
| Ĺ | 0.185 REF | | |
| L2 | 0.05 | 0.15 | |

GENERIC MARKING DIAGRAM*



= Specific Device Code Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

| STYLE 1: | STYLE 2: | STYLE 3: | STYLE 4: | STYLE 5: |
|--------------|---------------------------|---------------------------|-------------------------|--------------------------|
| PIN 1. BASE | PIN 1. ANODE | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. GATE |
| 2. EMITTER | 2. N/C | 2. ANODE | 2. CATHODE | SOURCE |
| 3. COLLECTOR | CATHODE | CATHODE | ANODE | 3. DRAIN |

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| DESCRIPTION: | SOT-1123, 3-LEAD, 1.0X0 | SOT-1123, 3-LEAD, 1.0X0.6X0.37, 0.35P | | |

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- C

SIDE VIEW

DATE 10 AUG 2009

NOTES:

- NOTES.

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD
- FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

| | MILLIMETERS | | | |
|-----|-------------|------|------|--|
| DIM | MIN | NOM | MAX | |
| Α | 0.45 | 0.50 | 0.55 | |
| b | 0.15 | 0.21 | 0.27 | |
| b1 | 0.25 | 0.31 | 0.37 | |
| С | 0.07 | 0.12 | 0.17 | |
| D | 1.15 | 1.20 | 1.25 | |
| E | 0.75 | 0.80 | 0.85 | |
| е | 0.40 BSC | | | |
| ΗE | 1.15 | 1.20 | 1.25 | |
| L | 0.29 REF | | | |
| 12 | 0.15 | 0.20 | 0.25 | |

L2 0.15 0.20 0.25

GENERIC MARKING DIAGRAM*



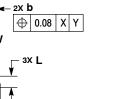
= Specific Device Code XX

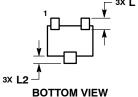
or not be present.

Μ = Date Code *This information is generic. Please refer to device data sheet for actual part

marking. Pb-Free indicator, "G", may

-X-2X b ⊕ 0.08 X Y **TOP VIEW** 3X L





STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

RECOMMENDED

0.40 2X 0.27 PACKAGE OUTLINE 1.50 3X 0.52 0.36

SOLDERING FOOTPRINT*

DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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| DESCRIPTION: | SOT-723 | | PAGE 1 OF 1 | |

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